

DESCRIPTION

The GLF1511 load switch is a fully integrated 4 A NMOS load switch with I_QSmart™ advanced technology. The device is ideal for the mobile computing and data storage markets as a high performance solution for load switch applications.

The GLF1511 provides a constant low on-resistance of 13 mΩ at the full input voltage range. The fixed rise time helps prevent undesirable inrush current when turned on and the internal EN pin pulldown resistor ensures the device remains in the shutdown mode when disabled. In shutdown mode the GLF1511 consumes ultra-low current at the wide input supply voltage.

The GLF1511 features a reverse current blocking protection. When the GLF1511 is disabled, it prevents reverse current flowing from the output to the input source.

The GLF1511 is available in a wafer level chip scale package (WLCSP) measuring 0.97 mm x 1.47 mm x 0.55 mm with a 0.5 mm pitch. This allows the user to save board space.

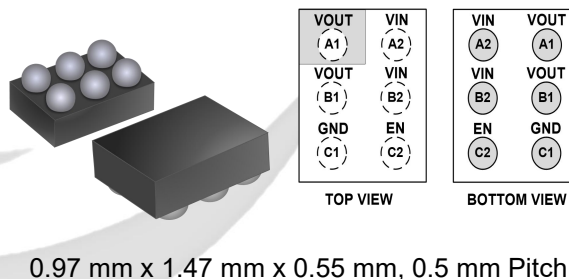
FEATURES

- Supply Voltage Range: 0.7 V to 5.5 V
- Low R_{ON}: 13 mΩ Typ
- I_{OUT} Max: 4 A
- Ultra-Low I_Q:
 - 2 μA Typ at 0.7 V_{IN}
 - 14 μA Typ at 3.3 V_{IN}
 - 30 μA Typ at 5.5 V_{IN}
- Ultra-Low I_{SD}:
 - 0.015 μA Typ at 0.7 V_{IN}
 - 0.030 μA Typ at 5.5 V_{IN}
- Controlled V_{OUT} Turn-on Time
- Internal EN Pull-Down Resistor
- Integrated Output Discharge Switch
- Reverse Current Blocking Protection When Disabled
- Operating Temperature Range: - 40 °C to 105 °C
- HBM: 8 kV, CDM: 2 kV
- 0.97 mm x 1.47 mm x 0.55 mm, 6 Bumps Wafer Level Chip Scale Package

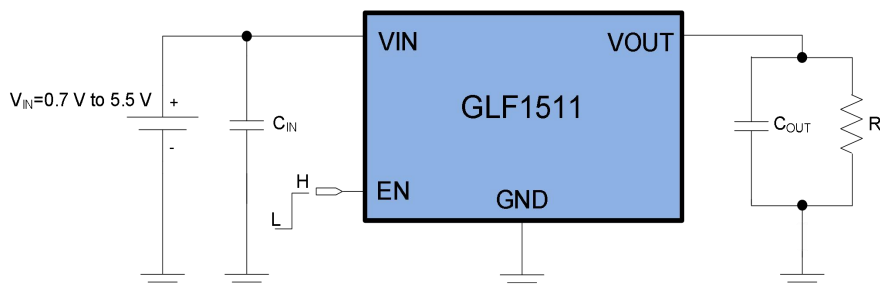
APPLICATIONS

- Data Storage, SSD
- Wearables
- Low Power Subsystems

PACKAGE



APPLICATION DIAGRAM



DEVICE ORDERING INFORMATION

Part Number	Top Mark	R _{ON} Typ. at Vin Range	Output Discharge	EN Activity
GLF1511	FL	13 mΩ	250 Ω	High

FUNCTIONAL BLOCK DIAGRAM

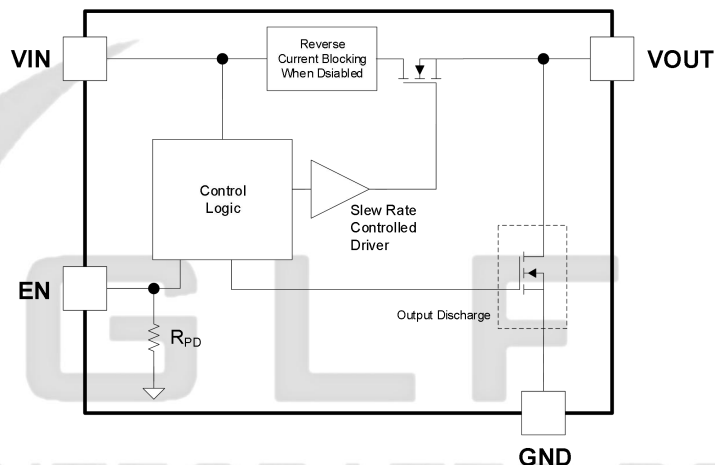
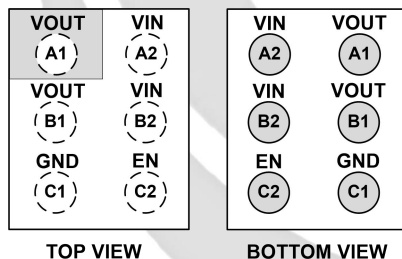


Figure 1. Functional Block Diagram

PIN CONFIGURATION



PIN DEFINITION

Pin #	Name	Description
A1, B1	VOUT	Switch Output
A2, B2	VIN	Switch Input. Supply Voltage for IC
C1	GND	Ground
C2	EN	Enable to control the switch

Figure 2. 0.97 mm x 1.47 mm x 0.55 mm WLCSP

ABSOLUTE MAXIMUM RATINGS

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions; extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter		Min.	Max.	Unit
V _{IN} , V _{OUT} , V _{EN}	Each Pin Voltage Range to GND		-0.3	6	V
I _{OUT}	Maximum Continuous Switch Current			4	A
P _D	Power Dissipation at T _A = 25 °C			1	W
T _{STG}	Storage Junction Temperature		-65	150	°C
T _A	Operating Temperature Range		-40	105	°C
θ _{JA}	Thermal Resistance, Junction to Ambient (board dependent)			85	°C/W
ESD	Electrostatic Discharge Capability	Human Body Model, JESD22-A114	8		kV
		Charged Device Model, JESD22-C101	2		

RECOMMENDED OPERATING CONDITIONS

Over operating temperature, unless otherwise noted

Symbol	Parameter	Min.	Max.	Unit
V_{IN}	Input Supply Voltage	0.7	5.5	V
V_{OUT}	Output Voltage Range	0	5.5	V

ELECTRICAL CHARACTERISTICS

$V_{IN} = 0.7\text{ V}$ to 5.5 V and $T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
Basic Operation						
I_Q	Quiescent Current	$EN = V_{IN}, I_{OUT} = 0\text{ mA}, V_{IN} = 0.7\text{ V}$		2	4	μA
		$EN = V_{IN}, I_{OUT} = 0\text{ mA}, V_{IN} = 1.0\text{ V}$		2.5		
		$EN = V_{IN}, I_{OUT} = 0\text{ mA}, V_{IN} = 2.5\text{ V}$		9		
		$EN = V_{IN}, I_{OUT} = 0\text{ mA}, V_{IN} = 3.3\text{ V}$		14		
		$EN = V_{IN}, I_{OUT} = 0\text{ mA}, V_{IN} = 5.5\text{ V}$		30	50	
		$EN = V_{IN}, I_{OUT} = 0\text{ mA}, V_{IN} = 5.5\text{ V}$	$T_A = 85\text{ }^{\circ}\text{C}^{(1)}$	54		
I_{SD}	Shutdown Current	$EN = \text{Disable}, I_{OUT} = 0\text{ mA}, V_{IN} = 0.7\text{ V}$		0.015		μA
		$EN = \text{Disable}, I_{OUT} = 0\text{ mA}, V_{IN} = 5.5\text{ V}$		0.030		
		$EN = \text{Disable}, I_{OUT} = 0\text{ mA}, V_{IN} = 5.5\text{ V}$	$T_A = 85\text{ }^{\circ}\text{C}^{(1)}$	0.83		
			$T_A = 105\text{ }^{\circ}\text{C}^{(1)}$	2.85		
R_{ON}	On-Resistance	$V_{IN} = 0.7\text{ V to } 5.5\text{ V}, I_{OUT} = 200\text{ mA}$	$T_A = 25\text{ }^{\circ}\text{C}$	13	20	$\text{m}\Omega$
			$T_A = 85\text{ }^{\circ}\text{C}^{(1)}$	16		
			$T_A = 105\text{ }^{\circ}\text{C}^{(1)}$	17		
R_{DSC}	Output Discharge Resistance	$V_{EN} = \text{Low}, I_{FORCE} = 2\text{ mA}$		250		Ω
V_{IH}	EN Input Logic High Voltage	$V_{IN} = 0.7\text{ V to } 1.5\text{ V}$	0.5			V
		$V_{IN} = 1.5\text{ V to } 5.5\text{ V}$	1.1			
V_{IL}	EN Input Logic Low Voltage	$V_{IN} = 0.7\text{ V to } 1.5\text{ V}$			0.15	
		$V_{IN} = 1.5\text{ V to } 5.5\text{ V}$			0.3	
R_{EN}	EN pull-down resistance	$V_{EN} = 3.3\text{ V}$		10		$\text{M}\Omega$
I_{EN}	EN Current	$V_{EN} = 5.5\text{ V}$			0.8	μA

Switching Characteristics ^{(1), (2)} $V_{IN} = 0.7\text{ V}$, $T_A = 25\text{ }^{\circ}\text{C}$

t_{dON}	Turn-On Delay	$R_L = 150\text{ }\Omega$, $C_{IN} = 1.0\text{ }\mu\text{F}$, $C_{OUT} = 0.1\text{ }\mu\text{F}$	145	μs
t_R	V_{OUT} Rise Time		190	
t_{dOFF}	Turn-Off Delay		38	
t_F	V_{OUT} Fall Time		17	

 $V_{IN} = 1.1\text{ V}$, $T_A = 25\text{ }^{\circ}\text{C}$

t_{dON}	Turn-On Delay	$R_L = 150\text{ }\Omega$, $C_{IN} = 1.0\text{ }\mu\text{F}$, $C_{OUT} = 0.1\text{ }\mu\text{F}$	120	μs
t_R	V_{OUT} Rise Time		240	
t_{dOFF}	Turn-Off Delay		8	
t_F	V_{OUT} Fall Time		18	

 $V_{IN} = 2.5\text{ V}$, $T_A = 25\text{ }^{\circ}\text{C}$

t_{dON}	Turn-On Delay	$R_L = 150\text{ }\Omega$, $C_{IN} = 1.0\text{ }\mu\text{F}$, $C_{OUT} = 0.1\text{ }\mu\text{F}$	90	μs
t_R	V_{OUT} Rise Time		310	
t_{dOFF}	Turn-Off Delay		2	
t_F	V_{OUT} Fall Time		18	

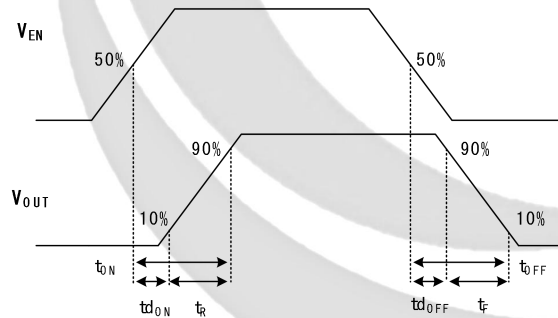
 $V_{IN} = 3.3\text{ V}$, $T_A = 25\text{ }^{\circ}\text{C}$

t_{dON}	Turn-On Delay	$R_L = 150\text{ }\Omega$, $C_{IN} = 1.0\text{ }\mu\text{F}$, $C_{OUT} = 0.1\text{ }\mu\text{F}$	80	μs
t_R	V_{OUT} Rise Time		360	
t_{dOFF}	Turn-Off Delay		1.5	
t_F	V_{OUT} Fall Time		18	

 $V_{IN} = 5.0\text{ V}$, $T_A = 25\text{ }^{\circ}\text{C}$

t_{dON}	Turn-On Delay	$R_L = 150\text{ }\Omega$, $C_{IN} = 1.0\text{ }\mu\text{F}$, $C_{OUT} = 0.1\text{ }\mu\text{F}$	70	μs
t_R	V_{OUT} Rise Time		360	
t_{dOFF}	Turn-Off Delay		1.5	
t_F	V_{OUT} Fall Time		18	

Notes: 1. By design; characterized, not production tested.

2. $t_{ON} = t_{dON} + t_R$, $t_{OFF} = t_{dOFF} + t_F$ **TIMING DIAGRAM****Figure 3. Timing Diagram**

TYPICAL PERFORMANCE CHARACTERISTICS

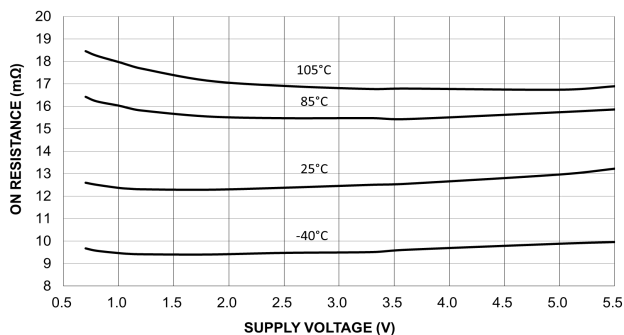


Figure 4. On-Resistance vs. Supply Voltage

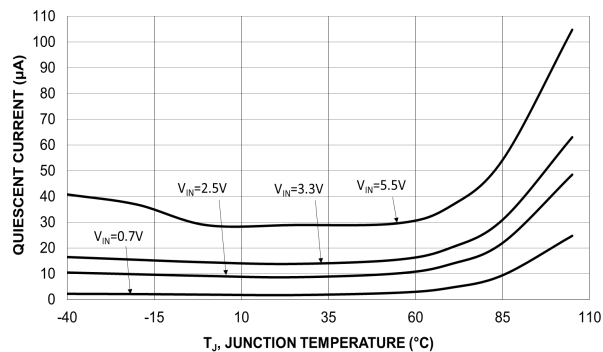


Figure 5. Quiescent Current vs. Temperature

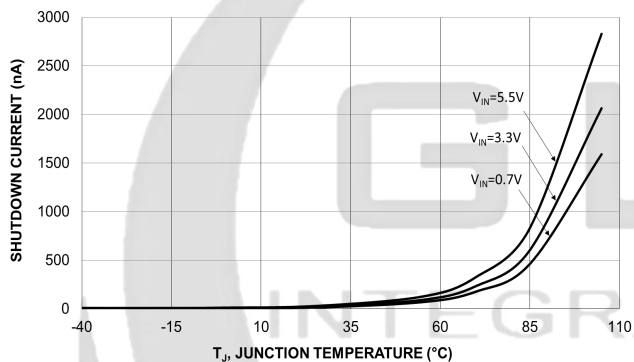


Figure 6. Shutdown Current vs. Temperature

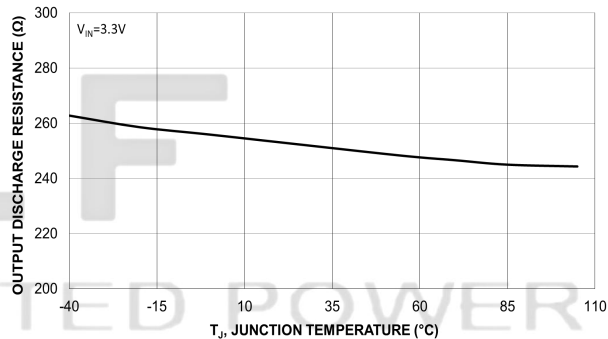


Figure 7. Output Discharge Resistance vs. Temperature

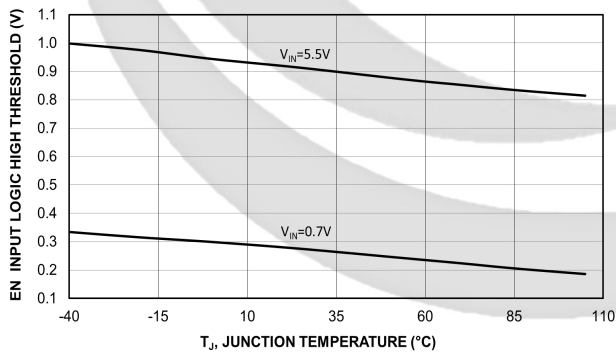


Figure 8. EN Input Logic High Threshold vs. Temperature

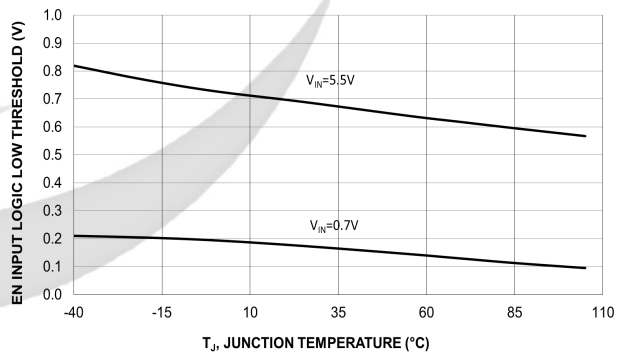


Figure 9. EN Input Logic Low Threshold vs. Temperature

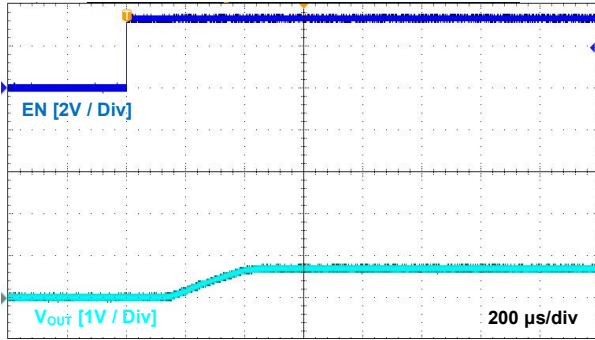


Figure 10. Turn-On Response
 $V_{IN}=0.7\text{ V}$, $C_{IN}=1.0\text{ }\mu\text{F}$, $C_{OUT}=0.1\text{ }\mu\text{F}$, $R_L=150\text{ }\Omega$

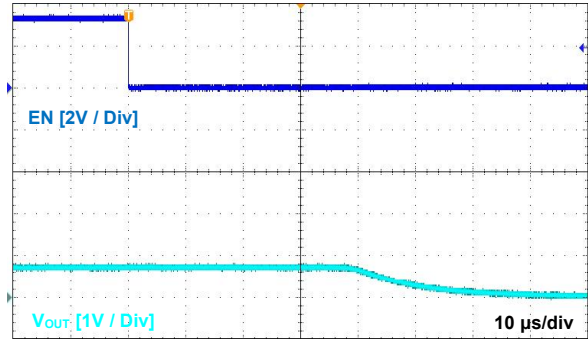


Figure 11. Turn-Off Response
 $V_{IN}=0.7\text{ V}$, $C_{IN}=1.0\text{ }\mu\text{F}$, $C_{OUT}=0.1\text{ }\mu\text{F}$, $R_L=150\text{ }\Omega$

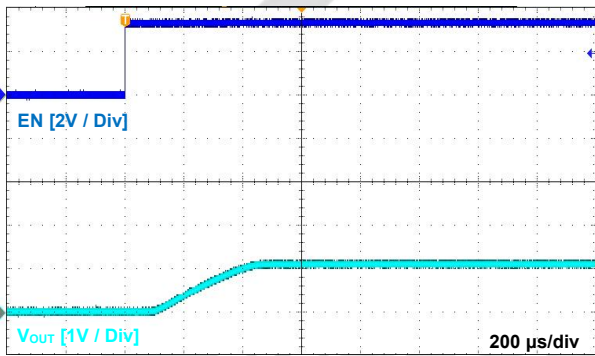


Figure 12. Turn-On Response
 $V_{IN}=1.1\text{ V}$, $C_{IN}=1.0\text{ }\mu\text{F}$, $C_{OUT}=0.1\text{ }\mu\text{F}$, $R_L=150\text{ }\Omega$

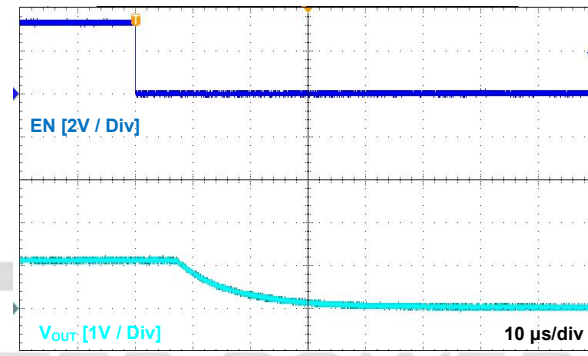


Figure 13. Turn-Off Response
 $V_{IN}=1.1\text{ V}$, $C_{IN}=1.0\text{ }\mu\text{F}$, $C_{OUT}=0.1\text{ }\mu\text{F}$, $R_L=150\text{ }\Omega$

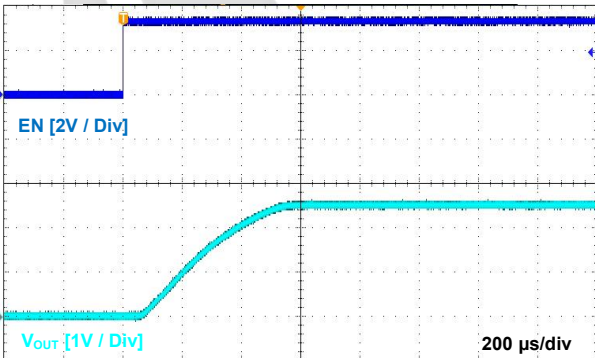


Figure 14. Turn-On Response
 $V_{IN}=2.5\text{ V}$, $C_{IN}=1.0\text{ }\mu\text{F}$, $C_{OUT}=0.1\text{ }\mu\text{F}$, $R_L=150\text{ }\Omega$

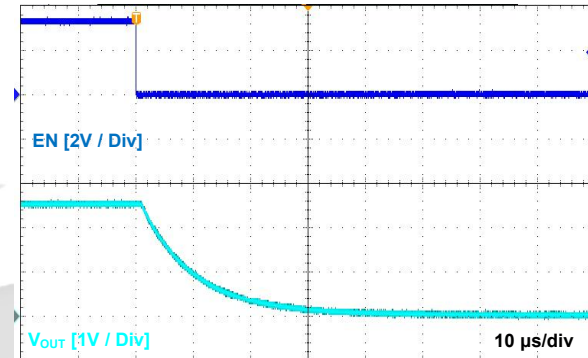


Figure 15. Turn-Off Response
 $V_{IN}=2.5\text{ V}$, $C_{IN}=1.0\text{ }\mu\text{F}$, $C_{OUT}=0.1\text{ }\mu\text{F}$, $R_L=150\text{ }\Omega$

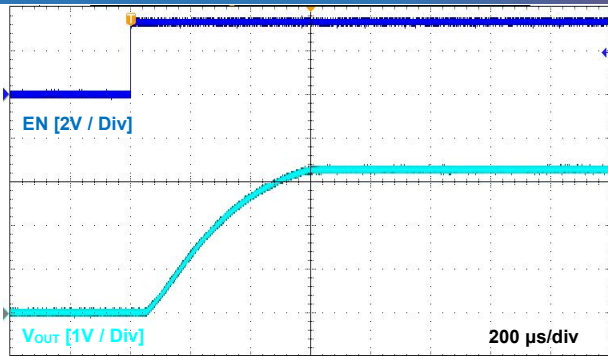


Figure 16. Turn-On Response
 $V_{IN}=3.3\text{ V}$, $C_{IN}=1.0\text{ }\mu\text{F}$, $C_{OUT}=0.1\text{ }\mu\text{F}$, $R_L=150\text{ }\Omega$

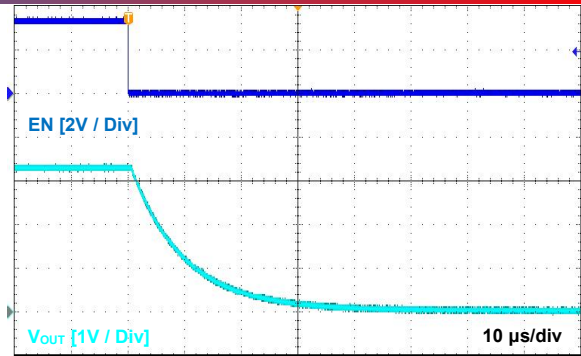


Figure 17. Turn-Off Response
 $V_{IN}=3.3\text{ V}$, $C_{IN}=1.0\text{ }\mu\text{F}$, $C_{OUT}=0.1\text{ }\mu\text{F}$, $R_L=150\text{ }\Omega$

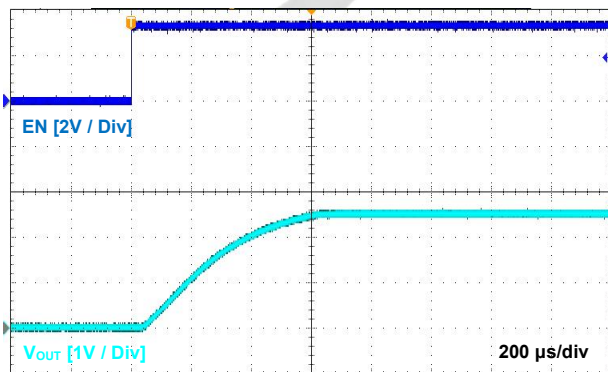


Figure 18. Turn-On Response
 $V_{IN}=5.0\text{ V}$, $C_{IN}=1.0\text{ }\mu\text{F}$, $C_{OUT}=0.1\text{ }\mu\text{F}$, $R_L=150\text{ }\Omega$

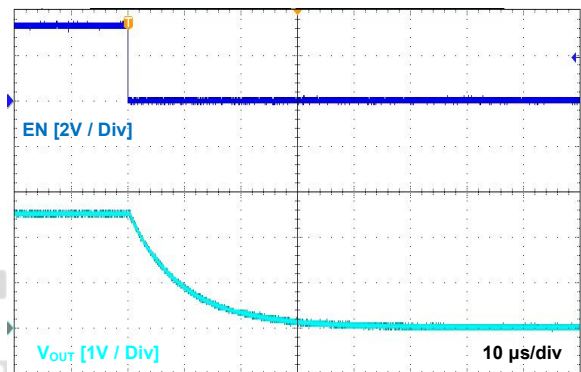


Figure 19. Turn-Off Response
 $V_{IN}=5.0\text{ V}$, $C_{IN}=1.0\text{ }\mu\text{F}$, $C_{OUT}=0.1\text{ }\mu\text{F}$, $R_L=150\text{ }\Omega$

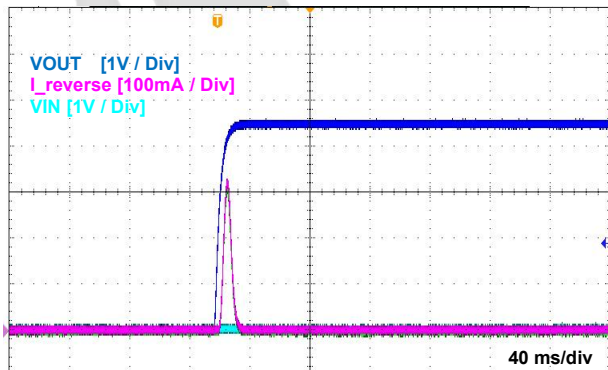


Figure 20. Reverse Current Blocking When Disabled
 $V_{IN}=V_{EN}=0\text{ V}$, $V_{OUT}=0\text{ V to }4.5\text{ V}$, $C_{IN}=1.0\text{ }\mu\text{F}$, $C_{OUT}=0.1\text{ }\mu\text{F}$

APPLICATION INFORMATION

The GLF1511 is a fully integrated 4 A NMOS load switch with fixed slew rate control to limit the inrush current during turn on. Each device is capable of operating over a wide input range from 0.7 V to 5.5 V with very low on-resistance to reduce conduction loss. In the off state, these devices consume very low leakage current, avoiding unwanted standby current from the input power supply. The GLF1511 is available in the 0.97 mm x 1.47 mm wafer level chip scale package with 6 bumps at 0.5 mm pitch to save space in compact applications.

Input Capacitor

A capacitor is recommended to be placed close to the V_{IN} pin to reduce the voltage drop on the input power rail caused by transient inrush current at start-up. A higher input capacitor value can be used to further attenuate the input voltage drop.

Output Capacitor

An output capacitor is recommended to minimize voltage undershoot on the output pin during the transition when the switch is turned off. Undershoot can be caused by parasitic inductance from board traces or intentional load inductances. If load inductances do exist, use of an output capacitor can improve output voltage stability and system reliability. The C_{OUT} capacitor should be placed close to the VOUT and GND pins.

Reverse Current Blocking

The GLF1511 has a built-in reverse current blocking protection. When the device is disabled, the reverse current blocking protection is activated to prevent the reverse current from the Vout to the Vin source.

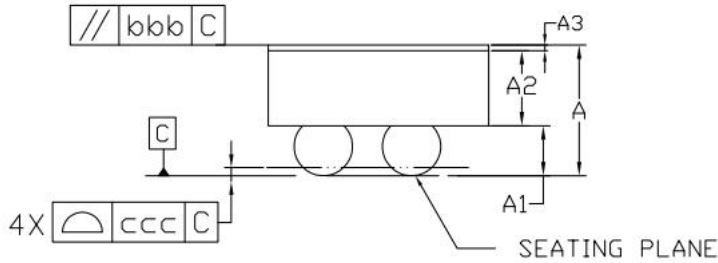
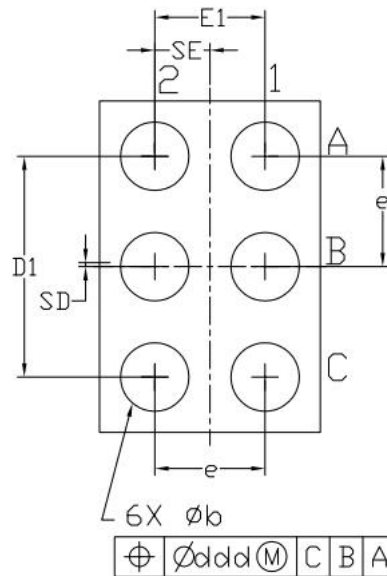
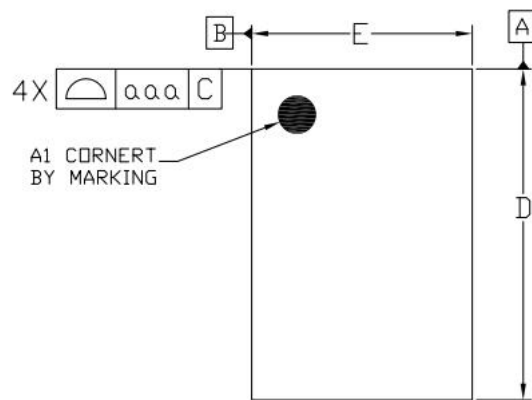
EN pin

The GLF1511 can be activated by EN pin high. Note that the EN pin has an internal pull-down resistor to maintain a reliable status without EN signal applied from an external controller.

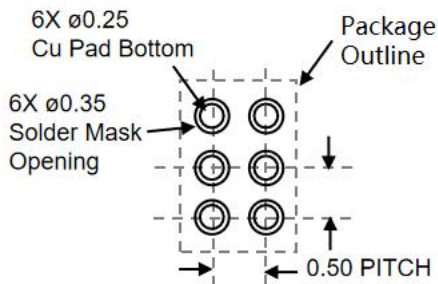
Board Layout

All traces should be as short as possible to minimize parasitic inductance effect. Wide traces for VIN, VOUT, and GND will help reduce signal degradation and parasitic effects during dynamic operations as well as improve the thermal performance at high load current.

PACKAGE OUTLINE



Recommended Footprint



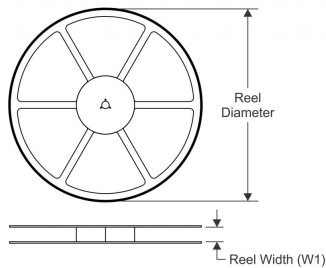
Dimensional Ref.			
REF.	Min.	Nom.	Max.
A	0.500	0.550	0.600
A1	0.225	0.250	0.275
A2	0.250	0.275	0.300
A3	0.020	0.025	0.030
D	1.460	1.470	1.485
E	0.960	0.970	0.985
D1	0.950	1.000	1.050
E1	0.450	0.500	0.550
b	0.260	0.310	0.360
e	0.500 BSC		
SD	0.000 BSC		
SE	0.250 BSC		
Tol. of Form&Position			
aaa	0.10		
bbb	0.10		
ccc	0.05		
ddd	0.05		

Notes

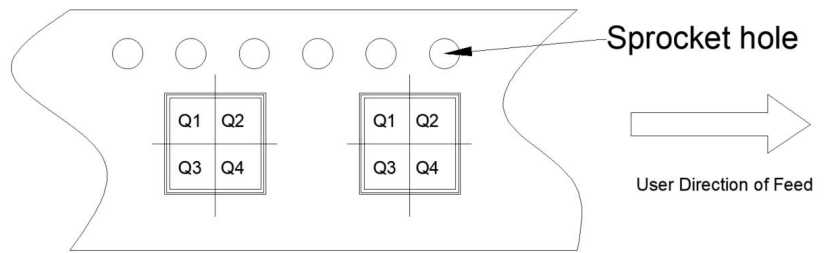
1. ALL DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGRESS)
2. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1994.
3. A3: BACKSIDE LAMINATION

TAPE AND REEL INFORMATION

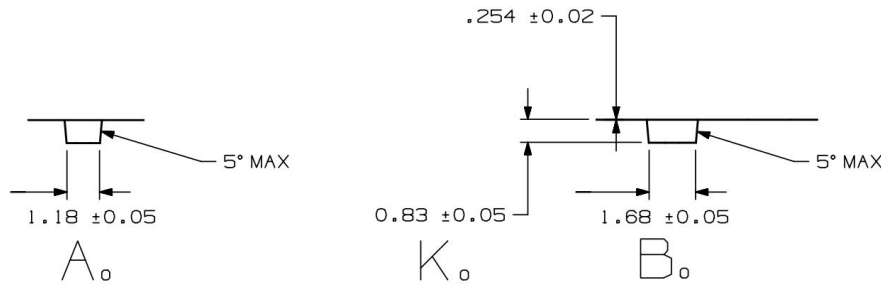
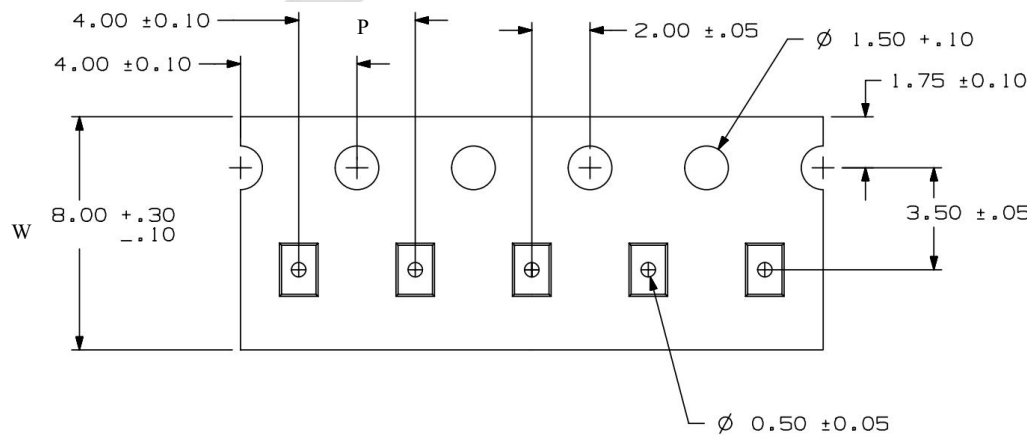
REEL DIMENSIONS



QUADRANT ASSIGNMENTS PIN 1 ORIENTATION TAPE



TAPE DIMENSIONS



Device	Package	Pins	SPQ	Reel Diameter (mm)	Reel Width W1	A0	B0	K0	P	W	Pin1
GLF1511	WLCSP	6	3000	180	9	1.18	1.68	0.83	4	8	Q1

Remark:

A0: Dimension designed to accommodate the component width

B0: Dimension designed to accommodate the component length

C0: Dimension designed to accommodate the component thickness

W: Overall width of the carrier tape

P: Pitch between successive cavity centers

SPECIFICATION DEFINITIONS

Document Type	Meaning	Product Status
Target Specification	This is a target specification intended to support exploration and discussion of critical needs for a proposed or target device. Spec limits including typical, minimum, and maximum values are desired, or target, limits. GLF reserves the right to change limits at any time without warning or notification. A target specification in no way guarantees future production of the device in question.	Design / Development
Preliminary Specification	This is a draft version of a product specification. The specification is still under internal review and subject to change. GLF reserves the right to change the specification at any time without warning or notification. A preliminary specification in no way guarantees future production of the device in question.	Qualification
Product Specification	This document represents the anticipated production performance characteristics of the device.	Production

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